Systematics in the superconducting and normal state properties in chemically substituted MgB_2

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The superconducting transition temperature, T_C, the residual resistivity ρ_0 and the slope of resistivity curve at high temperature, $d\rho/dT$, have been measured in a series of MgB_2 samples that have been chemically substituted to varying degree with Li or Cu at the Mg-site and by Li or Cu at the Mg-site along with C substitution at the B-site. DC resistivity and ac susceptibility measurements were employed to extract the above parameters. T_C versus the electron count (estimated from simple chemical valence count arguments) shows a universal behaviour, with T_C being constant at the MgB_2 value for electron counts lower than in MgB_2 but rapidly decreasing for larger electron counts. The temperature dependence of resistivity in the normal state fits to the Bloch- Gruneisen formula, from which the Debye temperature, θ_D, and the ρ_0 are extracted. θ_D variation with T_C is not systematic, whereas ρ_0 versus T_C shows a systematic variation that depends on the type of the chemical substituent. This dependence has a signature of the nature of the intraband/interband scattering affected by the chemical substitutions. $d\rho/dT$ increases with C substitution, but decreases with Li and Cu substitution, implying that C substitution leads to the domination of conductivity by the σ band, while in the Li/Cu substituted samples the π band dominates conduction.

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I. 1. INTRODUCTION

Starting with the discovery of superconductivity at 39K in MgB_2[1], there has been hectic activity both theoretical and experimental to unravel the origin of superconductivity in this system. The reduced isotope effect[2,3] and the negative pressure coefficient[4,5] of T_C seems to indicate that MgB_2 falls in the category of conventional electron-phonon coupled superconductors with a large electron phonon coupling constant[2,3]. Detailed band structure calculations performed on the system suggest that the Fermi surface consists of two cylinders arising from hole-like σ bonding bands and one electron like and another hole like 3-dimensional tubular network arising from the bonding and the antibonding π bands.[6,7] The phonon density of states has also been calculated for the system from which it is now clear that the E_{2g} phonon couples non- linearly with holes in the σ band and that it is also anharmonic.[8,9] The presence of both σ and π bands at the Fermi surface and their different couplings with the phonons result in a k-dependent superconducting gap[10] hitherto not observed in earlier superconductors. An effective two gap superconductivity seems sufficient to describe the anomalous specific heat and tunneling data in MgB_2.[11,12] Evidence for multigap superconductivity is now accruing from scanning tunneling microscopy , Raman scattering and point contact spectroscopy.[13,14,15]

Various chemical substitutions have been carried out primarily to increase T_C and to verify several of the early theoretical predictions. The substituents at Mg site that have been examined are Al,[16,17,18] Si,[19] alkali metals,[20,21,22] 3d transition metals[23,24,25] and 4d transition metals.[26,27] These substitutions have almost always resulted in a decrease in T_C, irrespective of whether the substituent is an electron dopant or a hole dopant, with the exception of Zn substitution in which an increase in T_c of $\sim$0.2K was observed. This increase was found to correlate with an expansion of the lattice.[23,24] A similar correlation of the volume expansion with a T_C increase was also observed in our previous study on 4d- transition metal substitution in MgB_2 where a small ($\sim$0.5K) increase in T_C was observed for 5% Nb substitution in MgB_2.[27] One of the systems studied in detail has been $Mg_{1-x}Al_xB_2$[16] in which T_C shows a monotonic decrease with substitution in the x=0.0 to x=0.3 composition range, there is an abrupt decrease in T_C at x=0.33, beyond which again a monotonic decrease in T_C is observed[17]. There is also an associated compression along the c-axis and along the a-axis resulting in a net decrease in the cell volume. Thermopower studies in this series showed that the charge carriers are holes and the decrease in T_C correlates with the decrease in the hole density of states at the Fermi level[18] as a result of electron doping in the system. Band structure calculations carried out in Al substituted MgB_2 indicates a decrease in the area of the cylindrical part of the Fermi surface with substitution, which also correlates rather well with the decrease in T_C with Al substitution.[28] Be substitution in $MgB_{2-x}Be_x$, results in a decrease in a- lattice parameter and in an increase in c- lattice parameter resulting in a net increase in volume, and phase stability in this system was observed upto x=0.6. Thermopower measurements showed an increase in hole concentration with Be substitution. Thus in the Be substituted samples despite an increase in cell volume and an increase in the hole concentration, T_C decreases. It is reasoned that the decrease in T_C is correlated with the decrease in 'a' lattice parameter which leads to a depletion of charge at the B site, causing an increase in phonon frequency and decrease in electron phonon coupling.[29,30] Carbon substitution at B site,[31,32,33,34,35,36] reported by different groups

showed a decrease in T_C and cell volume with increase in C content. The decrease in T_C is attributed to a decrease in hole density of states at the Fermi level due to electron doping. The small differences in the extent of decrease in T_C among the various reports arise on account of the differences of C solubility into the MgB_2 lattice. This variation in solubility has been attributed to the form of C employed in the synthesis and the method of sample preparation. We have reported[36] a C solubility upto x=0.30 in $MgB_{2-x}C_x$ and a decrease in T_C of upto ∼26K in these samples, made using a home built 50 bar pressure lock-in set-up. The decrease in T_C with C concentration matches with that observed for Al substitution, possibly indicating that the additional electrons due to C/Al substitution fill the MgB_2 bands in a rigid band manner. From the substitution studies, discussed above, it is clear that electron doping results in a decrease in T_C, and an increase in T_C due to hole doping has not been observed.

Calculations[37] predicted an increase in T_C by complete substitution of Mg by Cu and partial C substitution of B in the MgB_2 lattice. The rationale behind the prediction was that C substitution for B would result in an increase in stiffness of B-C bond and hence the electron-phonon coupling strength. Since C substitution results in electron doping, known to deplete T_C, it was thought that substitution of Cu for Mg would provide the compensating holes in the system. Search along similar lines led to the prediction of hole doped LiBC to be a high temperature superconductor,[38] in which the presence of the B-C network results in a large electron-phonon interaction.

Early band structure calculations[7] also point out that the hole DOS in MgB_2 is 2-dimensional in character and that an increase in the hole concentration may not result in an increase in T_C. It was shown that hole DOS is flat below E_F, i.e:, will remain constant with hole doping but falls off slowly with a small increase in electron doping and rather precipitously beyond 0.2 electron addition per formula unit. In our earlier study on C doped MgB_2, we indeed did see a large decrease in T_C with large electron dopings, which could be attributed to a precipitous decrease in the hole DOS. In an attempt to check the hole DOS picture further, we started out on the synthesis of samples with differing hole concentration levels by suitable Li and Cu substitution and have examined the variation in T_C in them with electron addition by C substitution. The two initial hole dopings we started out with were 20% Li substituted and 5% Cu substituted MgB_2. These compositions were arrived at based on the determination of individual solubilities of Cu and Li in MgB_2 by systematic chemical substitution studies of Cu and Li respectively.

The different series of samples that are examined in this work are, Li and Cu substitution at Mg site to study the effect of holes viz., $Mg_{1-x}Li_xB_2$ and $Mg_{1-x}Cu_xB_2$ and electron doping by C substitution at B site along with hole doping of 20%Li and 5%Cu at the Mg site, viz., $Mg_{0.80}Li_{0.20}B_{2-x}C_x$ and $Mg_{0.95}Cu_{0.05}B_{2-x}C_x$. The experimental techniques employed in this study are ac susceptibility measurement for determining T_C and resistivity measurement from 300K to 4.2K, to determine T_C and normal state transport. The superconducting transition temperatures are extracted from the onset of the diamagnetic signal and from the zero resistance. The temperature dependent normal state resistivity is fitted to the Bloch- Gruneisen formula to extract the Debye temperature θ_D and residual resistivity ρ_0. Using this θ_D and the measured T_C in the McMillan equation, the electron-phonon coupling λ is extracted. The slope of the linear part of the resistivity curve in the 200K-300K temperature range has also been determined in each of the samples, in order to quantify the magnitude of the temperature dependence of resistivity. The various measured parameters on these samples have been compared with that in $MgB_{2-x}C_x$.[36] The paper is organized as follows. In section.2 the experimental details are mentioned. In section.3 we present the various results along with the corresponding discussions in different subsections. Section.4 provides the summary and conclusions.

II. 2. EXPERIMENTAL

Samples of nominal composition $Mg_{1-x}Li_xB_2$ [x=0.1, 0.2, 0.3], $Mg_{1-x}Cu_xB_2$ [x=0.01, 0.02, 0.025, 0.05], $Mg_{0.80}Li_{0.20}B_{2-x}C_x$ [x=0.1, 0.2] and $Mg_{0.95}Cu_{0.05}B_{2-x}C_x$ [x=0.025, 0.05, 0.15, 0.3] were prepared by the standard solid-vapour technique using Mg powder (99.9%), amorphous boron (99%), carbon soot (99%) obtained from fullerene synthesis, Li pieces (99%) and Cu powder (99.9%). The stoichiometric quantities are weighed, mixed and compacted into a Ta crucible and heat treated at 900^0C for 1hour 30 minutes under a locked-in Ar pressure of 50 bar.[36] Li was loaded inside a dry box under Ar atmosphere. Weight loss was consistently recorded to be less than 1% indicating that the nominal composition is preserved even after the heat treatment in all the samples. Samples so obtained were of ∼30% theoretical density and suitable for resistivity measurements by appropriate slicing. However some samples that were not compacted properly, resulted in porous powders, in which resistivity contacts could not be achieved. The samples were characterized by powder X-ray diffraction in a STOE diffractometer using Cu-K_α radiation in the Bragg-Brentano geometry. Susceptibility measurements were done by tracing the diamagnetic signal using an ac mutual inductance technique at a measuring frequency of 941 Hz for which 25 mg of finely powdered samples were used. The resistance measurements were done on ∼1mm thick sliced pieces in the standard four probe geometry using, 42 SWG Cu leads with silver paint as contact glue. The resistivity in each sample was measured in the Van der pauw geometry at room temperature, using which resistivity values at all the temperatures could be determined.

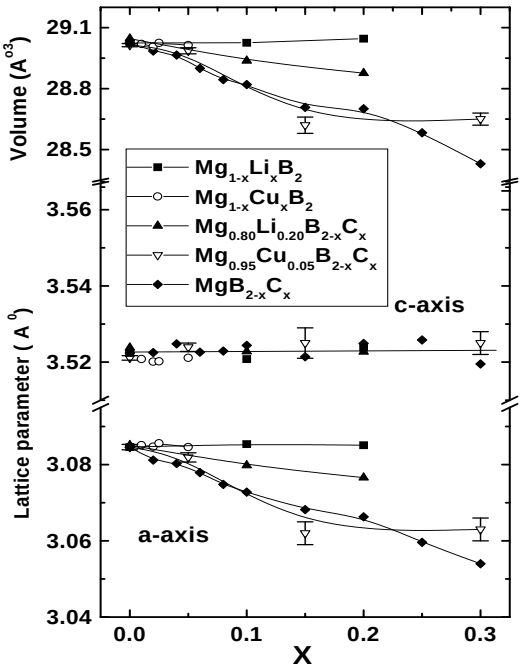

FIG. 1: Plot of the lattice constants 'a' and 'c' and the lattice cell volume, obtained from XRD patterns, as a function of the varying substituent fraction,'x'. The solid lines are guide to the eye.

For both susceptibility and resistivity measurements, the temperature variation from 300K to 4.2K was obtained by using a dipstick setup in the which the temperature was measured using a Si-diode thermometer with an excitation current of 10μA and the data was collected through a PC, interfaced by IEEE 488 card.

III. 3. RESULTS AND DISCUSSION

A. 3.1 XRD measurements

From the phase purity analysis of the XRD data it is clear that the Li solubility in MgB_2 is at least 20% (x=0.2), while that of Cu is only 5% (x=0.05). Carbon substitutes upto a fraction of x=0.30 in a phase pure form in the cation substituted samples. The lattice parameters 'a' and 'c' and the cell volume obtained from an analysis of the XRD data using the STOE program are shown in Fig. 1, as a function of 'x', where x is the fraction of the substituent whose concentration is varied in that particular series. It can be seen from the figure that 'c' parameter remains more or less unchanged with substitution in all the series studied. For cationic substitutions, the 'a' parameter also remains constant, resulting in no change in volume for samples that are substituted only at the Mg site. The lack of change in the lattice parameters with Li substitution in Fig. 1 is at variance with earlier studies[20] where a substantial decrease in 'a' parameter was observed with Li substitution. From Fig. 1, it is seen that with C substitutions the lattice parameter along 'a' decreases monotonically with increasing concentration with a corresponding decrease in the lattice volume. The extent of the decrease is the largest for the $MgB_{2-x}C_x$, intermediate in $Mg_{0.95}Cu_{0.05}B_{2-x}C_x$ and small in $Mg_{0.80}Li_{0.20}B_{2-x}C_x$. The lattice constant remaining unchanged in the Li substituted samples can be rationalized based on the fact that the ionic radii of Li^+ of Mg^{++} are not very different. The lack of change due to Cu substitution can be reconciled with, from the fact that Cu is soluble only to 5% and a difference in the ionic radii may not reflect as a measurable change in lattice constant. The decrease in the a-parameter with C content can result due to the smaller covalent radius of C in comparison with that of B. The smaller decrease in the a-parameter with C substitution in the Li and Cu substituted samples is surprising. The differences in these lattice parameter variations suggest that the electron concentration present in the sample also plays an important role in determining the equilibrium lattice constants.

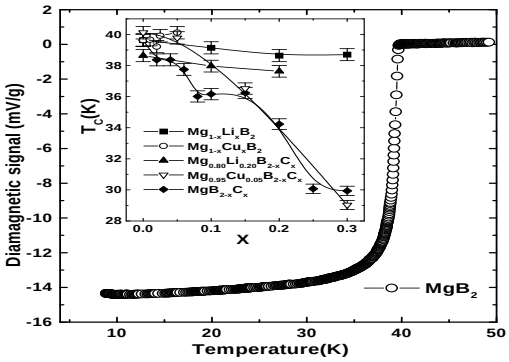

FIG. 2: Plot of diamagnetic signal versus temperature in the range 4.2K-50K for pristine MgB_2. In the inset is shown the variation in T_C with fraction 'x' of varying substituent in the different series studied. The temperature at the 10% signal measured from the onset is taken as T_C.

TABLE I: Table.1 Data from susceptibility measurements; temperature corresponding to 10% of the total diamagnetic signal, measured from the onset ie recorded T_C; difference between the temperatures corresponding 10% signal and 90% signal is recorded as ΔT_C and the corresponding magnitude of the signal is the volume fraction.

$Mg_{1-y}M_yB_{2-x}C_x$	M	y	x	T_c	ΔT_c(K)	Vol.Frac.(mV/gm)
MgB_2		0	0	39.6	1.75	14.0
$MgB_{2-x}C_x$		0	0.02	38.3	2.41	12.9
		0	0.04	38.4	4.13	13.6
		0	0.06	37.7	4.51	13.1
		0	0.08	36.0	4.11	12.8
		0	0.10	36.1	8.08	13.5
		0	0.15	36.2	9.17	11.3
		0	0.20	34.2	14.09	11.5
		0	0.25	30.1	14.66	11.9
		0	0.30	29.9	15.12	9.0
$Mg_{1-y}Li_yB_2$	Li	0.1	0	39.1	4.5	7.8
		0.2	0	38.8	4.9	7.6
		0.3	0	38.7	5.7	4.9
$Mg_{0.8}Li_{0.2}B_{2-x}C_x$		0.2	0.1	38.0	3.3	9.6
		0.2	0.2	37.6	5.9	10.1
$Mg_{1-y}Cu_yB_2$	Cu	0.01	0	39.7	3.2	7.1
		0.02	0	39.2	3.5	9.7
		0.025	0	39.9	2.7	8.7
		0.05	0	40.11	2.8	7.7
$Mg_{0.95}Cu_{0.05}B_{2-x}C_x$		0.05	0.05	39.8	3.4	8.5
		0.05	0.15	36.5	8.8	6.6
		0.05	0.30	29.0	9.5	4.9

B. 3.2 T_C from ac susceptibility and from dc resistivity

In Fig.2 is shown the variation of the diamagnetic signal for MgB_2 in the 4.2K to 50K temperature range. The T_C of 39.6K is deduced by reading off the value of temperature at 10% of the total diamagnetic signal determined from the onset. The transition width (ΔT_C), determined from the difference in temperatures at 90% and 10% of the total diamagnetic signal, was 1.75K. The variation of T_C along each series is shown in the inset of Fig.2. The observed values of T_C, ΔT_C and volume fraction of the net diamagnetic signal for the various samples are tabulated in Table.1. [width=8cm,height=8cm]

In Fig.3 is shown the temperature dependence of resistivity curve for pristine MgB_2. The value of RR defined as

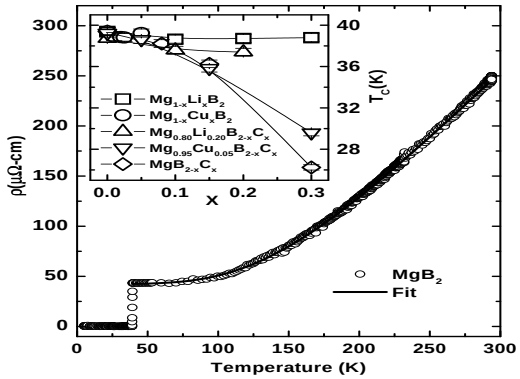

FIG. 3: Fig. 3 Plot of the resistivity versus temperature from 4.2K-300K for pristine MgB_2. The solid line shows the fitted curve resistivity curve to the Bloch-Gruneisen formula. In the inset is shown the variation in T_C with the fraction of substituent x for the different series studied. Solid lines in the inset are a guide to the eye.

the ratio of the resistivity at 300K to the resistivity at 40K (ρ(300K)/ρ(40K)), observed for MgB_2 was ∼6 with a T_C of 39.4K at zero resistance, and the transition width ΔT_C determined as the difference in the onset and downset temperature is ∼0.3K. The T_C variation across the different series, is shown in the inset of Fig.3 and in Table. 2. The variation of T_C as a function of substituent from the resistivity data is in general agreement with that observed by susceptibility measurements. It is clear from Fig.3 that in the series $Mg_{1-x}Cu_xB_2$, T_C remains almost constant, whereas in $Mg_{1-x}Li_xB_2$ it shows a small decrease. The transition width is ∼0.3K for all these concentrations. In contrast, in all the carbon substituted samples a systematic decrease in T_C is seen and the extent of decrease in T_C is dependent on the amount of cation substituted. Across the series $Mg_{0.95}Cu_{0.05}B_{2-x}C_x$ a decrease in the T_C of 10K for a maximum carbon substitution of x=0.3 is observed, compared to a T_C decrease of 14K in the $MgB_{2-x}C_x$ series for a comparable carbon content. Whereas, in the $Mg_{0.80}Li_{0.20}B_{2-x}C_x$ series only a decrease of ∼1K is observed and the transition width is also very small of ∼0.5K for all the samples in this particular series. For the other carbon substitutions, as in susceptibility measurements the transition width is seen to increase with the degree of substitution. The differences in the variation of T_C for a similar extent of carbon substitution, therefore hints at the dependence of T_C on other factors. We investigate one such possibility below.

C. 3.4 T_C versus electron count

We define a parameter N_{excess}, denoting the excess charge (electron/hole) with respect to MgB_2 as

$$N_{excess} = x - y \tag{1}$$

where, x is the fraction of the divalent anion substituent (assumed to donate one electron in excess of MgB_2 for each atom substituted per formula unit) and y is the fraction of monovalent cation (which supplies one extra hole as compared to that in MgB_2 for one atom substituted per formula unit). The general formula for a representative sample studied is given by $Mg_{1-y}M_yB_{2-x}C_x$, where M=Li or Cu. N_{excess} can be taken as a qualitative measure of the valence electron concentration, with respect to that in MgB_2. N_{excess} is zero for MgB_2, positive for electron doped MgB_2 and negative for hole doped MgB_2. A plot of N_{excess} against T_C is shown in Fig.4, from which it is clear that the T_C remains almost constant for $N_{excess} < 0$ viz., with increase in the hole concentration in MgB_2, whereas it decreases with increase in electron concentration viz., for $N_{excess} > 0$. The prominent feature in Fig.4 is that T_C variation is the same for all the samples, albeit they belong to different series, depending purely on the electron count in the sample. To illustrate this point, focusing at N_{excess}=0 in Fig.4, obtained from MgB_2, $Mg_{0.80}Li_{0.20}B_{1.80}C_{0.20}$ and $Mg_{0.95}Cu_{0.05}B_{1.95}C_{0.05}$, one sees that the T_Cs are nearly the same. The T_C versus N_{excess} plot in Fig.4 holds a striking resemblance to the hole DOS versus energy curve shown by An and Pickett.[7] It was remarked in that paper that T_C will not increase with hole doping whereas electron doping would result in a decrease in T_C. From Fig.4

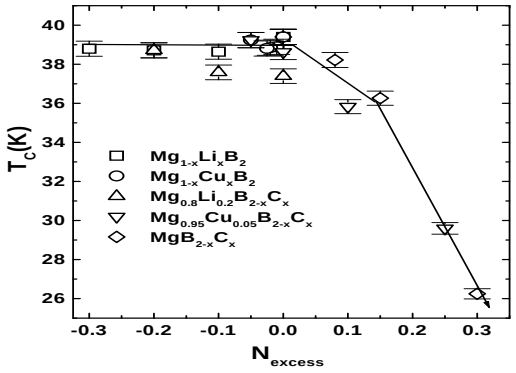

FIG. 4: Plot of N_{excess} (defined in the text) against T_C for all the samples. The symbols for the different series are marked in the legend. The solid line is a guide to the eye.

TABLE II: Data from resistivity measurements; x, y and N_{excess} are described in the text. The temperature corresponding to zero resistivity is shown as T_C; θ_D, ρ_0, ρ_1 parameters obtained from fitting the normal state resistivity to the Bloch-Gruneisen formula; electron-phonon interaction parameter, λ calculated using McMillan's equation and the slope of ρ(T) in the 200K-300K range.

$Mg_{1-y}M_yB_{2-x}C_x$	N_{excess} (x-y)	T_C (K)	θ_D (K)	ρ_0 $\mu\Omega$-cm	$\rho_1 x10^{-3}$ $\mu\Omega$-cmK^{-2}	Cx10^3 $\mu\Omega$-cmK	λ	dρ/dT
MgB_2	0	39.4	911.9	41.92	0.2536	3.6761	0.8408	1.2083
$MgB_{1.92}C_{0.08}$	0.08	38.2	823.4	173.76	1.4118	2.4189	0.8784	1.3238
$MgB_{1.70}C_{0.30}$	0.30	26.2	528.8	948.2	3.339	1.2801	0.9123	2.2609
$Mg_{0.90}Li_{0.10}B_2$	-0.10	38.6	992.7	30.079	0.5079	1.9901	0.8015	0.7683
$Mg_{0.80}Li_{0.20}B_2$	-0.20	38.7	920.1	22.651	0.2011	0.9223	0.8335	0.3779
$Mg_{0.80}Li_{0.20}B_{1.90}C_{0.10}$	-0.10	37.6	851.9	99.569	0.2705	1.5426	0.8545	0.6343
$Mg_{0.80}Li_{0.20}B_{1.80}C_{0.20}$	0	37.4	674.4	271.69	1.3174	2.6158	0.9755	1.6238
$Mg_{0.99}Cu_{0.01}B_2$	-0.01	38.9	936.5	20.550	0.2587	1.1867	0.8280	0.4510
$Mg_{0.98}Cu_{0.02}B_2$	-0.02	38.8	963.4	34.245	0.4864	1.8878	0.7594	0.7715
$Mg_{0.975}Cu_{0.025}B_2$	-0.025	38.8	928.7	16.971	0.2625	1.0823	0.8305	0.4480
$Mg_{0.95}Cu_{0.05}B_2$	-0.05	39.2	852.6	27.226	0.2506	1.4668	0.8780	0.6276
$Mg_{0.95}Cu_{0.05}B_{1.95}C_{0.05}$	0	38.6	800.1	43.603	0.3159	1.3653	0.8979	0.6455
$Mg_{0.95}Cu_{0.05}B_{1.85}C_{0.15}$	0.10	35.8	785.9	137.64	0.2789	1.1841	0.8698	0.5686
$Mg_{0.95}Cu_{0.05}B_{1.70}C_{0.30}$	0.25	29.6	851.9	235.43	0.4922	0.8002	0.7594	0.4978

it appears that the T_C remains fixed with hole doping, whereas it shows a decrease with electron doping, which is smooth upto an electron doping level of ∼0.2, beyond which T_C drops faster in agreement with the calculation.[7]

D. 3.5 Analysis of normal state resistivity

The temperature dependence of the normal state resistivity in MgB_2, suggests the dominance of phonon scattering.[39,40,41] The normal state resistivity for each of the data from the different series investigated could be fitted to the Bloch-Gruneisen formula, in the 40K and 300K range[41] using

$$\rho(T) = \rho_0 + \rho_1 T^2 + C\rho_{ph}(T) \quad (2)$$

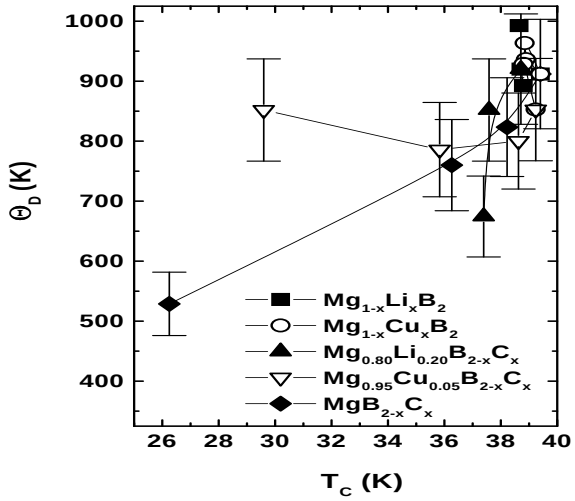

FIG. 5: Plot of T_C against θ_D obtained from the Bloch-Gruneisen fit for all samples studied. Solid lines are guides to the eye.

where ρ_{ph}(T) is given by

$$\rho_{ph}(T) = (m-1)\theta_D(\frac{T}{\theta_D})^m \int_0^{\frac{\theta_D}{T}} dZ \frac{Z^m}{(1-e^{-z})(e^z-1)} \tag{3}$$

ρ_0 is the impurity scattering contribution to resistivity, ρ_1 denotes the magnitude of the electron-electron interaction parameter, m=5, θ_D is the Debye temperature and C is a constant. The fit obtained for MgB_2, is shown in Fig.3 along with the experimental data, from which it is apparent that the fit is excellent. A similar quality of fit has been obtained for each of the ρ(T) data in all the series. From the fit, the value of ρ_0, ρ_1, C and θ_D were extracted, which are shown in Table 2. The small values of ρ_1 suggest that the contribution from electron-electron scattering to the transport is negligible in the system. The ρ_0 obtained from the Bloch-Gruneisen fits are in close agreement with ρ(40K), the measured resistivity prior to the superconducting transition. It can be seen from Table. 2 that θ_D decreases with C substitution, but the extent of the observed decrease is very large in comparison to that expected from mass considerations alone. In the case of Li and Cu substitutions viz., $Mg_{1-x}M_xB_2$ (M=Li,Cu), θ_D is seen to remain constant, even though a large increase in θ_D in the former and decrease in the latter is expected. Carbon substitution on Li substituted samples also shows a similar decrease in θ_D as in $MgB_{2-x}C_x$. But with Carbon substitution, in the 5% Cu substituted samples θ_D remains constant in contrast to the decrease observed in $MgB_{2-x}C_x$ and $Mg_{0.80}Li_{0.20}B_{2-x}C_x$ samples. These θ_D variations versus the observed T_C are shown in Fig.5, from which it is apparent that a systematics does not emerge. It should however be mentioned that the lack of systematics could have its origin on the fact that the Bloch-Gruneisen fits have been made assuming that the conductivity arises from a single dominant band; which is known to be true for pristine MgB_2. The good fits to this formula would imply the dominance of single band in the substituted samples also, excepting for the fact that the dominant band could be different as will become apparent from the sections to follow.

From the McMillan equation,

$$T_c = (\frac{\theta_D}{1.45})exp[-\frac{1.04(1+\lambda)}{(\lambda-\mu^*(1+0.62\lambda)}] \tag{4}$$

using the measured T_C and the extracted θ_D, the electron phonon coupling constant, λ is computed with μ^*=0.15. The calculated values (cf. Table 2) for the entire series falls in the range of 0.7 and 1.0, which is in general agreement with values reported from theoretical calculations and specific heat measurements.

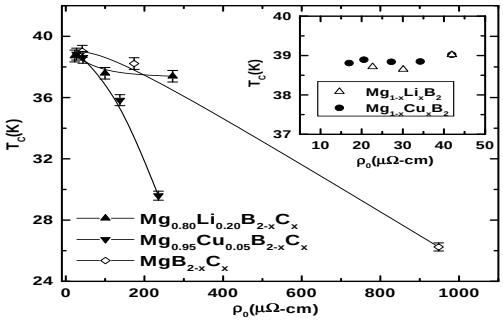

FIG. 6: Plot of ρ_0 versus T_C where ρ_0 is the residual resistivity obtained from the Bloch-Gruneisen fit of the normal state resistivity data, in all the series studied. Inset shows the data in the Cu and Li substituted samples. The solid lines are a guide to the eye.

E. 3.6 ρ_0 versus T_C correlation

In the MgB_2 system Matthiesen's rule is violated in that samples that have a large residual resistivity also show a stronger temperature dependence of resistivity.[42] Further, despite the fact that impurity scattering is detrimental to superconductivity in a multiband system,[44] T_C is robust to the residual resistivity variations in MgB_2. These issues have been discussed in a recent calculation[43], which suggest that the absence of interband scattering between the σ and π bands in MgB_2 and the dominance intraband σ-σ and π-π scattering is primarily responsible for this unusual behaviour. It has been shown that the unique electronic structure of MgB_2 makes σ-π hybridization unfavourable, an important pre-requisite for the occurrence of an interband scattering event. Further it has also been demonstrated that by introduction of scattering sites in the Mg sublattice, σ-π hybridization is not significantly altered. Calculating the T_C for different intraband/interband scattering ratios, it has been shown that the slope of the plot of ρ_0 versus T_C which is negligible for large intraband scattering cross section increases progressively with increase in interband scattering. These results have been compared with the experimental T_C values that have been obtained for pristine MgB_2 from different laboratories.

Since in our present study the T_C and the resistivity behaviour has been examined for a variety of chemical substitutions at the Mg-site, B-site and both Mg and B sites, it appears appropriate to see if any systematics in the variation of ρ_0 with T_C can be discerned from our data. In Fig.6 is shown the plot of ρ_0 versus T_C for the different series examined in this work. From Fig.6 it is clear that there is a systematic variation of T_C with ρ_0 within each series. In the inset of Fig.6 is shown the variation of T_C with ρ_0 by monovalent cation substitution, which appears almost flat. Taking the cue from calculations[43], these results suggest that the electronic conduction in the cation substituted samples is dominated by intraband scattering.[43] In the C substituted series the variation of T_C with ρ_0 is much larger for similar extents of substitution. For example in $Mg_{0.95}Cu_{0.05}B_{2-x}C_x$, the fall of T_C with ρ_0 is largest, followed by that in $MgB_{2-x}C_x$, and it is smallest for the Li substituted system viz., $Mg_{0.80}Li_{0.20}B_{2-x}C_x$. Comparing this with the calculated variation of T_C with ρ_0,[43] clearly suggests that the interband scattering starts playing a role in determining ρ_0 in the carbon substituted samples. This increase in interband scattering could arise from the presence of an excess p_z electron at the C in the B layer, resulting in the an enhanced σ- π hybridization. This hybridization may get further accentuated in the Cu substituted samples due to the presence of 3d orbitals of Cu, leading to an increased interband scattering and consequently in the pronounced variation of ρ_0 with T_C in these samples (cf. Fig. 6).

F. 3.7 Slope of high temperature resistivity

In order to obtain a quantitative measure of the temperature dependence of resistivity in the various samples, the magnitude of $d\rho/dT$ from the linear regime of $\rho(T)$ can be extracted. In Fig.7a and Fig.7b are shown the $\rho(T)$ data

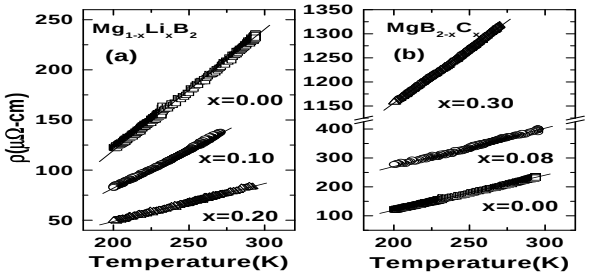

FIG. 7: ρ(T) in the 200-300K range (a)in $Mg_{1-x}Li_xB_2$ and in (b) $MgB_{2-x}C_x$, the solid lines are the linear fits to the data.

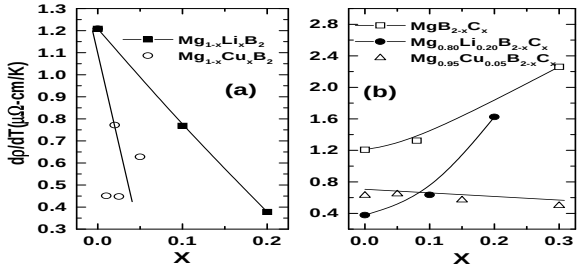

FIG. 8: A plot of dρ/dT versus the fraction substituted, for (a)cation substituted samples and (b) for carbon substituted samples. The solid lines are a guide to the eye.

in the 200K-300K temperature range for two representative series viz., $Mg_{1-x}Li_xB_2$ and $MgB_{2-x}C_x$. It is clear from the Figure that in the Li substituted samples the slope decreases, while in the C substituted samples the dρ/dT increases with substitution. Similarly the slopes are obtained from a linear fit of the ρ(T) data in all the samples and are tabulated in Table.2, and also shown in two panels for the cation substituted samples and carbon substitutions in Fig.8a and Fig.8b respectively. A feature that clearly emerges from the data is that the slope decreases by a large extent due to Mg substitution, implying the temperature dependence of ρ(T) decreases in these samples with substitution. In contrast, in the carbon substituted samples i.e., in $MgB_{2-x}C_x$ and in $Mg_{0.80}Li_{0.20}B_{2-x}C_x$ the slope increases with the level of C substituted (cf. Fig. 8b), indicating that the temperature dependence of ρ(T) increases with substitution. The degree of increase in dρ/dT is also high in both the series. In the $Mg_{0.95}Cu_{0.05}B_{2-x}C_x$ series, however, dρ/dT shows a small decrease. Plotted in Fig.9a and Fig.9b in two panels is the variation of ρ_0 in the different series with substitution. The variation in dρ/dT and ρ_0 with the concentration of the substitutent are very similar excepting in the $Mg_{0.95}Cu_{0.05}B_{2-x}C_x$ series.

In order to obtain a qualitative understanding of the variation in ρ_0 and dρ/dT in the various series we take recourse to an analysis of the conductivity in terms of the two band model thought to be most appropriate to understand

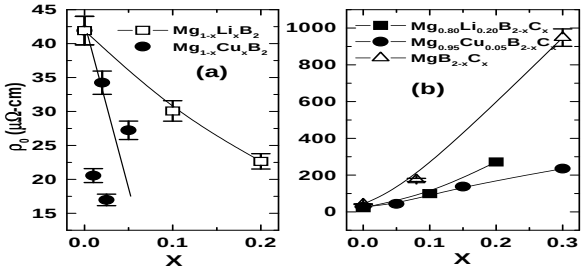

FIG. 9: A plot of ρ_0 versus the substituted fraction in the different series, (a) cation substituted samples (b) carbon substituted samples. The solid lines are a guide to the eye.

normal state transport in MgB_2.[43] The expression for conductivity in a two band model[43] is given by

$$\frac{1}{\rho(T)} = \frac{1}{4\pi} \sum_{n=\sigma,\pi} \frac{\omega_{pl,n}^2}{W_n(0,T)}, \tag{5}$$

where $\omega_{pl,n}$ is the plasma frequency for the band 'n' and $W_n(0,T)$ for n=σ band is given by

$$W_\sigma(0,T) = \gamma_\sigma + \frac{\pi}{T} \int_0^\infty d\omega \frac{\omega}{sinh^2(\frac{\omega}{2T})} [\alpha_{tr}^2(\omega) F_{\sigma\sigma}(\omega) + \alpha_{tr}^2(\omega) F_{\sigma\pi}(\omega)] \tag{6}$$

where $\gamma_\sigma = \gamma_{\sigma\sigma} + \gamma_{\sigma\pi}$, and $\gamma_{nn'}$ is the transition probability for an electron to scatter from band index n to n' and $\alpha_{tr}^2(\omega) F_{nn'}(\omega)$ are the transport Eliashberg functions. The expression $W_\pi(0,T)$ can be obtained by substituting π for σ in Eq. (6). It is clear from the Eq. (5) that if the σ band i.e; if the first term in Eq. (5) dominates, the temperature dependence of conductivity will be large, since this band is known to couple strongly with phonons in MgB_2. On the other hand if the π band dominates conduction, the temperature dependence of conductivity will be small as the π band couples less effectively with phonons in this system. The reduced $d\rho/dT$ in the cation substituted samples(cf. Fig.8a) and the enhanced $d\rho/dT$ in the C substituted samples (cf. Fig. 8b) therefore imply that the π band dominates conduction in the former and the σ band dominates conduction in the latter.

The domination of the σ band in the carbon substituted samples ($MgB_{2-x}C_x$ and $Mg_{0.80}Li_{0.20}B_{2-x}C_x$) would be possible if either the plasma frequency for that band is large or if the $\gamma_{\pi\pi}$ is large in Eq.5. Since it has been inferred from band structure calculations that the $\omega_{pl,\sigma}$[42,43] is small in MgB_2, it appears that $\gamma_{\pi\pi}$ is large in the C substituted samples. This increase in the $\pi-\pi$ scattering, could arise due to the presence of disorder along the C-axis as a result of the proximity of the p_z electrons of carbon to this region. The increase in the $d\rho/dT$ with increase in C content would naturally follow due to the progressive increase in $\gamma_{\pi\pi}$ consequent to an increase in the number of such scattering centres. The increase in ρ_0 with C substitution which is clearly seen from panels showing the C substitutions in Fig. 9b could arise due to increase in $\gamma_{\sigma\pi}$, which is also apparent from Fig.6. In the $Mg_{0.95}Cu_{0.05}B_{2-x}C_x$ series the interband scattering term $\gamma_{\sigma\pi}$ is very large (cf. Fig.6). This could make both the σ and π channels of conduction in Eq.5 equally probable, because of which drawing inferences about the behaviour of either ρ_0 or $d\rho/dT$ becomes difficult.

The behaviour of $d\rho/dT$ in the cation substituted samples shows that despite substitution in Mg sublattice the observed temperature dependence of $\rho(T)$ is smaller than in MgB_2, contrary to the findings of the theoretical calculations[43] which indicate that the $\gamma_{\pi\pi}$ would be large, leading to the domination of the conductivity by the σ band. However the larger contribution to conductivity from the π band (term2 Eq.5), observed in the cation substituted samples (cf. Fig. 8a) could occur if the relative magnitudes of the plasma frequencies from the σ and π bands get strongly affected due to these substitutions. This is highly plausible as it has been demonstrated from band structure calculations of LiB_2[42] that the band disposition and dispersion are strongly altered with respect to that in

MgB_2. It can be seen from Fig. 9a that ρ_0 decreases with substitution in the cation substituted samples, a result rather surprising. These would imply that the intraband $\pi - \pi$ scattering is progressively reduced due to these substitutions. Band structure calculations would be necessary to verify these experimental observations. Measurements of the normal stste resistivity in the $Mg_{1-x}Al_xB_2$ in which detailed band structure calculations exists are in progress.

IV. 4. SUMMARY AND CONCLUSION

The variation of T_C has been studied as a function of the variation in electron and/or hole concentration by appropriate chemical substitutions. A plot of T_C versus the electron count estimated from the different series studied shows a universal behaviour, remaining flat for electron counts lesser than the MgB_2 value whereas it steeply decreases with electron count in excess of that in MgB_2. This has a striking similarity with the variation of hole DOS with energy. The ratio of the interband/intraband scattering seems to be strongly affected by the nature of the chemical dopant. The addition of C to the Boron layer seems to increase $\gamma_{\sigma\pi}$ resulting in an increase in the residual resistivity and to the depletion of T_C, which gets further enhanced due to Cu substitution in the Mg sub-lattice. The slope of the resistivity curve in the 200K-300K, gives an indication of the magnitude of the temperature dependence. The larger temperature dependence in the C substituted samples indicates that the σ-band dominates conduction in this system. The temperature dependence of resistivity in the monovalent cation substituted samples are lowered with respect to that in MgB_2, suggesting an enhanced participation in conductivity due to the π-bands. These results clearly demonstrate that by selective chemical substitutions conductivity from certain bands can be probed.

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